



## Short Communication

# Photoelectrochemical cell

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Received 13<sup>th</sup> December 2016, revised 12<sup>th</sup> July 2017, accepted 30<sup>th</sup> July 2017

## Abstract

The photoresponse of chemically synthesized polyaniline (PAn) film has been studied. PAn, casted in the form of film, on ITO glass substrate formed the photoanode, 0.1 M aqueous LiClO<sub>4</sub> solution has been used as electrolyte and platinum as counter electrode. This photocell shows good performance.

**Keywords:** Polyaniline, Photocell.

## Introduction

In recent few decades many researchers have focused their work in one of the most important source of energy i.e Solar energy. Fujishima Honda<sup>1</sup> was the first scientist who had suggested the applications of semiconductor polymers in liquid junction for solar energy conversion. A new field of research has been created by the generation of photocurrent due conjugated polymers in liquid junction. This field is different from the photo electrochemistry of conventional solid crystalline semiconductors. Due to low manufacturing cost of semiconductor polymers, these polymers will have a wide range of possibilities for technological application not only in photo electrochemical cell but also in photo anodes. Previously in order to resist the anodic photo corrosion of negative type semiconductors in liquid junction<sup>2</sup> conductive polymers were used. It is observed similar effect by covering various negative type semiconductors with PAn. I-V characteristics of such materials are studied<sup>3</sup>.

If light with sufficient energy more than band gap is fall on conducting polymers than charge carriers are generated due to photoelectric effect. These generated charge carriers are unstable in nature. Such a way charge carriers are generated which result in photocurrent. This mechanism in poly (trans-acetylene) have been explained by Pokhodenko et al<sup>4</sup>. Photo response of the order 10μA was reported at a depletion layer of polyaniline of a p-type semiconductor in an aqueous LiClO<sub>4</sub> solution<sup>4,5</sup>. In LiClO<sub>4</sub> reduced form of PAn shows 100μA photocurrent at saturation<sup>6</sup>. This type of PEC cells were explained without addition of redox species in the electrolyte solution.

It was observed that after inclusion of redox species stability of photocurrent in PAn increases under the continuous irradiation<sup>7</sup> of light. Fernando et al<sup>8</sup> had studied the rapid photoresponse current component of PAn.

Photocurrent produced by the external circuit in a reduced form of PAn having higher energy band gap is observed to be a weak signal. Thus in this situation small number of electron-hole pairs are produced due to low photocurrent density.

From the literature survey it was found that most of the photoelectrochemical studies of polyaniline have been carried out using cyclic voltametry for the synthesis of polyaniline. In the present work chemically synthesized PAn in the form of transparent and thin film has been used as a photoanode to study the photoelectrochemical response.

## Materials and methods

**Preparation of photoanode:** Half area of conducting ITO glass plate was covered by coating film of clear solution of polyaniline in formic acid. Conducting glass was obtained from Chemical Physics Division, TIFR, Mumbai. The film showed electrical conductivity of about 10<sup>-1</sup>Scm<sup>-1</sup>. Copper wire was used to create a contact lead, with one of its end sealed over the PAn film with the help of epoxy (Araldite). The SnO<sub>2</sub> layer of ITO glass works as back contact for PAn – formic acid film. All the portion of ITO glass on which film was not deposited was also sealed with epoxy. Such a way photoanode with thickness of 0.2 to 0.3 μm was prepared.

**Cathode:** Platinum was used as counter electrode (cathode).

**Reference electrode:** Here we use Standard calomel electrode as reference electrode.

**Electrolyte:** 0.1 M aqueous solution of LiClO<sub>4</sub> was used as electrolyte to study photoelectric effect of PAn.

**Fabrication of Photocell:** Figure-1 shows PEC cell where semiconducting thin film of formic acid-PAn is used, 0.1 M aqueous LiClO<sub>4</sub> solution is used as an electrolyte. Tungsten halogen lamp of 150 watt has been used as a light source.

The face of photoanode was illuminated with this source of light. The intensity of illumination was varied using variac which was connected to the halogen lamp. The intensity of illumination was measured with the help of a lux meter.

Current - voltage characteristics – For studying the current – voltage characteristics of PEC cell, it is necessary to select proper intensity of light for illumination of the cell.  $I_{sc}$  and  $V_{oc}$  both depend on light intensity. In experimental observation  $V_{oc}$  and  $I_{sc}$  reaches its maximum value as they increase with intensity of light. This maximum value attended by them is at light intensity of  $70\text{mW}/\text{cm}^2$  or above.

It is also observed that  $I_{ph}$  and  $V_{ph}$  varies with  $R_L$  for a steady illumination of PEC by  $70\text{mW}/\text{cm}^2$ .

### Results and discussion

Figure-2 shows  $I_{ph}$ - $V_{ph}$  characteristics for the thin films of PAN-formic acid photoanode exposed to constant light intensity of  $70\text{mW}/\text{cm}^2$ . From these characteristics parameters like  $I_{sc}$ ,  $V_{oc}$ ,  $I_{max}$ , and  $V_{max}$  have been obtained.

The maximum output power of the cell ( $P_m$ ) has been calculated using the relation

$$P_m = I_m \times V_m = V_{oc} \times I_{sc} \times ff$$

Where:  $ff$  is the fill factor,  $V_m$  and  $I_m$  have been calculated from  $I_{ph}$ - $V_{ph}$  curve for maximum power.

$ff$  has been calculated from the relation

$$ff = \frac{I_m \times V_m}{V_{oc} \times I_{sc}}$$

Hence the value of fill factor decided the quality of PEC<sup>9</sup>.

The efficiency of such a solar cell is,

$$\eta = \frac{V_{oc} \times I_{sc} \times ff}{P_{in}} \times 100\% \quad \text{or} \quad \eta = \frac{P_m}{P_{in}} \times 100\%$$

Where:  $P_{in}$  is maximum power at  $70\text{mW}/\text{cm}^2$  in this case.

From the  $I_{ph}$ - $V_{ph}$  plot the fill factor is calculated and is found to be 0.3, the efficiency ( $\eta$ ) of the PEC cell is obtained as 1.3.

The stability of the PEC cell is also tested by plotting  $I_{ph}$  v/s time for fixed value of intensity. The plot  $I_{ph}$  versus time is shown in Figure-3. From this plot it can be observed that the photocurrent initially increases and after 2-3 minutes of illumination, the photocurrent reaches maximum value. After that the current slowly falls off and becomes almost steady after about 20 minutes. Thus using this type of PEC cell, almost steady current of about  $20\mu\text{A}$  can be obtained with constant illumination with  $70\text{mW}/\text{cm}^2$ . Thus light intensity can be used as E.M.F. of a cell using a simple formic acid doped polyaniline thin film.

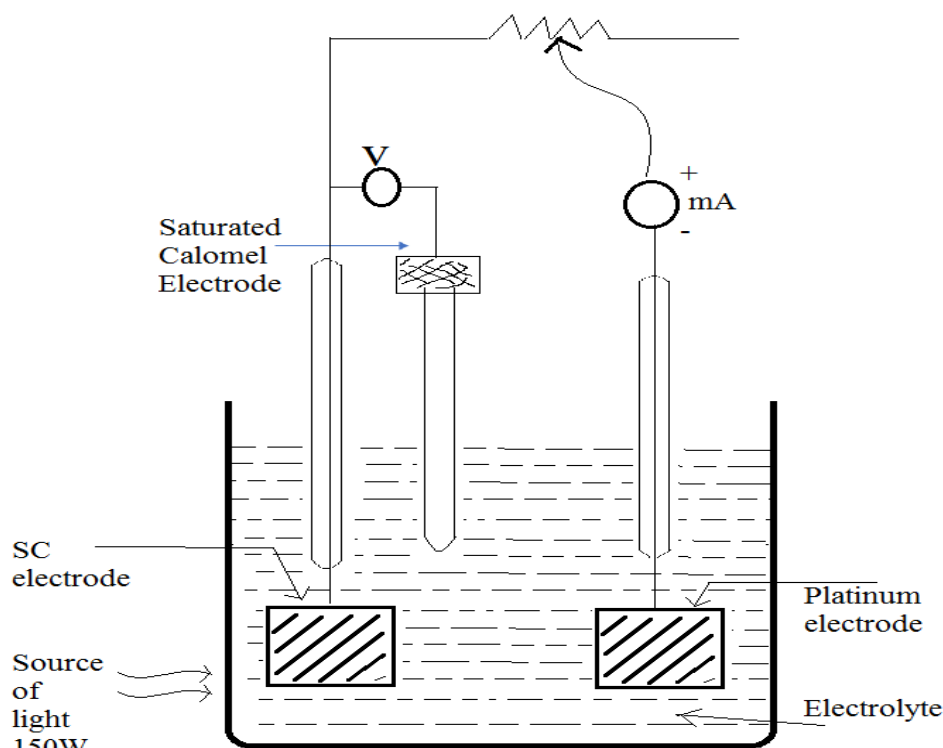
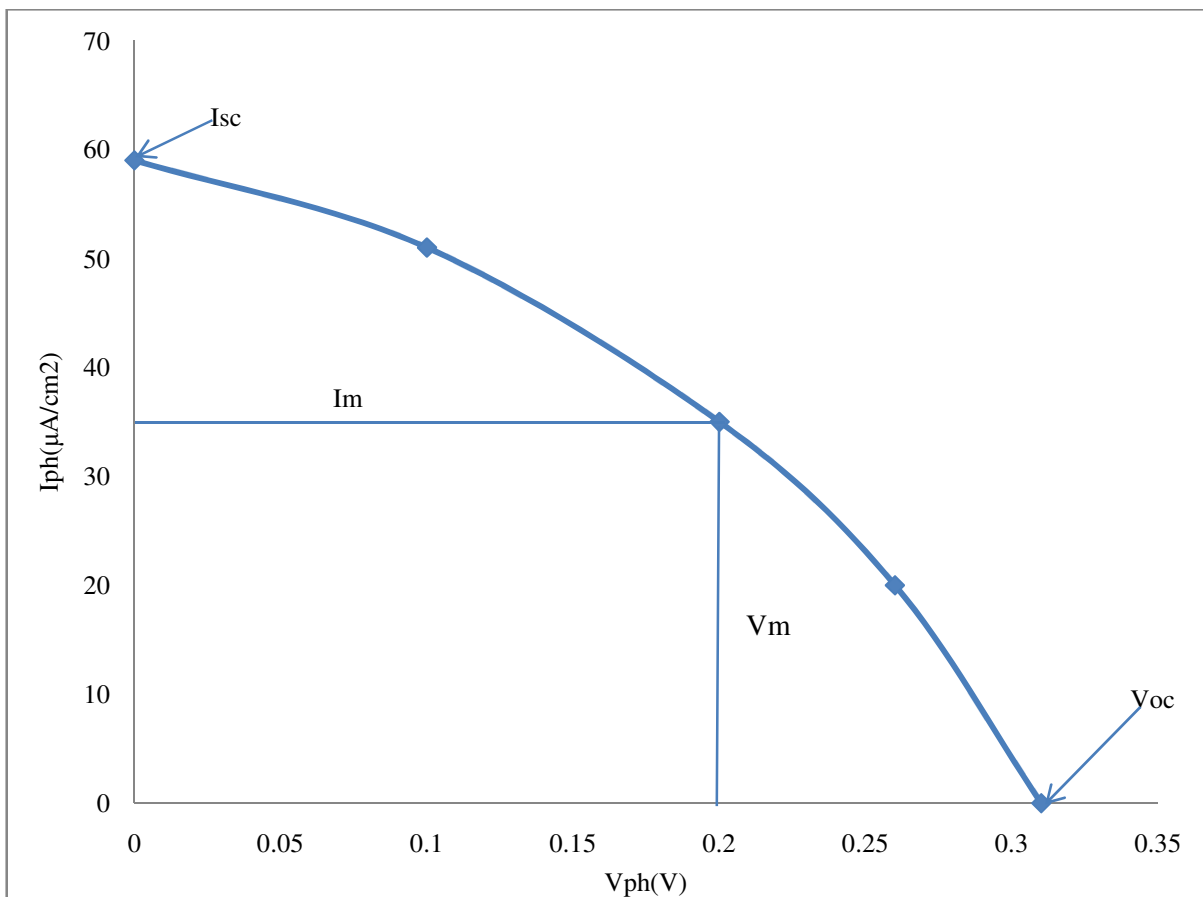
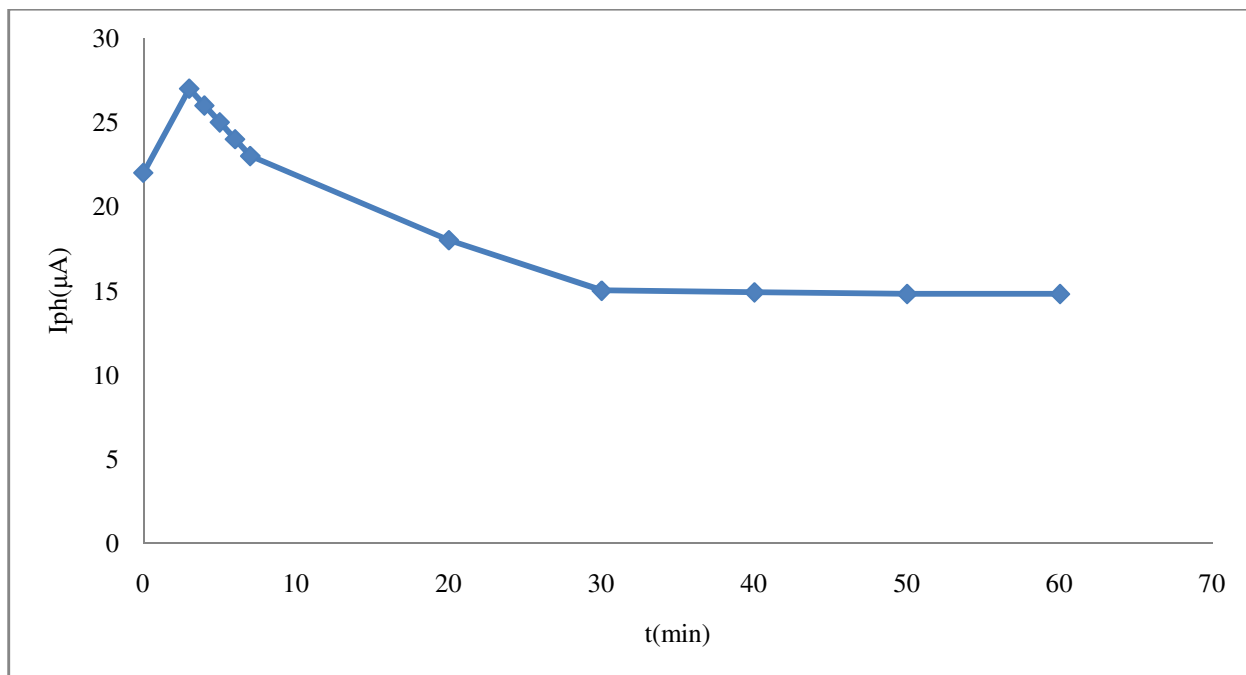


Figure-1: Photoelectrochemical Cell.



**Figure-2:** Photocurrent-photovoltage characteristics of HCOOH-PAN photoanode (Tungsten-halogen, 70 mW/cm<sup>2</sup> illumination at room temperature.)



**Figure-3:** Photocurrent density ( $I_{ph}$ ) as a function of time ( $t$ ) of illumination of photoelectrochemical cell. HCOOH-PAN film/LiClO<sub>4</sub>/ITO for 1 KΩ load.

## Conclusion

Solar cell using PAn film shows promising results with efficiency of 1.3. With further research efficiency of PAn film can be increased.

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